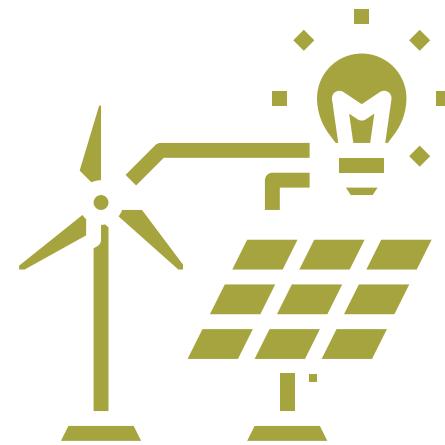


DIAMFAB
DIAMOND ENHANCED TECHNOLOGIES

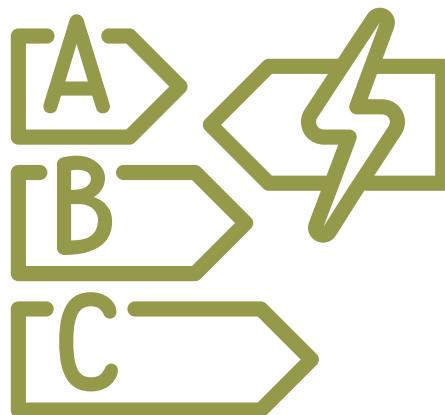
The next generation of semiconductors
"HARDER, BETTER, FASTER, STRONGER"



Key trends towards a decarbonized economy



Carbon free electricity production



Energy efficiency improvement

We need to avoid
36,3
giga-ton^s 
from fossil fuel

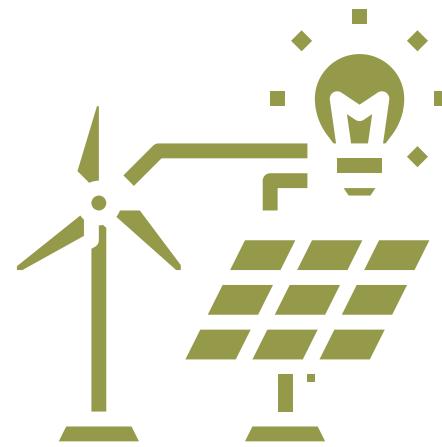


Electrification of mobility,
transportation and industry
process

H2

Alternative carbon free fuels

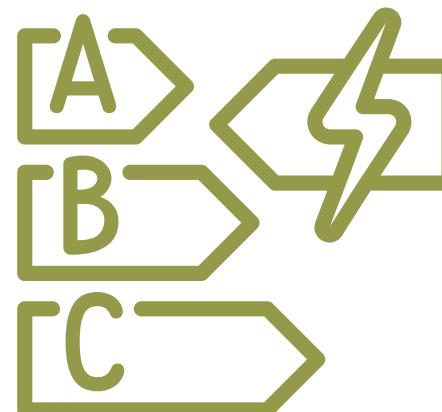
Power Semiconductor: a key decarbonation enabler



POWER
CONVERSION
for distribution



POWER
CONVERSION
for motor management



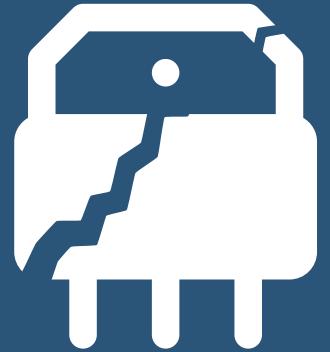
POWER
CONVERSION
for better efficiency



POWER
CONVERSION
for H₂ production (electrolysis)

Silicon limits are reached

Silicon can no longer be used for efficient energy management.



Devices limited to 1200 V



10 % energy lost at each conversion



Heavy converters because of
bulky cooling system (limited
temperature operation)

DIAMOND

F O R P O W E R E L E C T R O N I C S



x30

Higher
voltage/Si



x5000

Higher current
density/Si



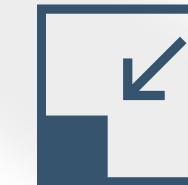
>400°C

Higher temperature
operation



>1 MGy

Radioactivity
withstand



80 %

Lighter & smaller converter

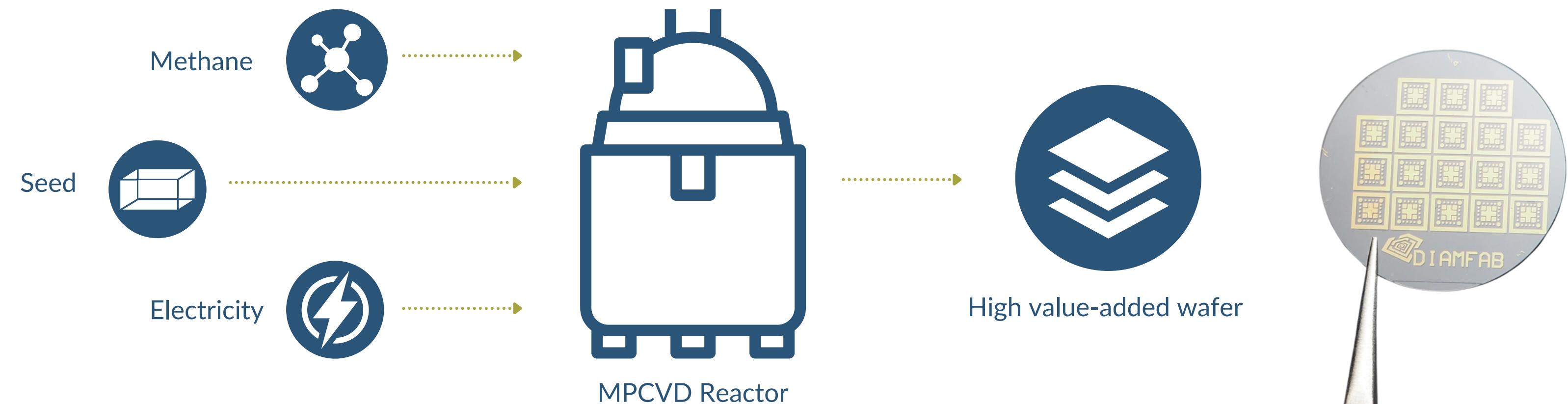


90 %

Less energy losses

FOR MINIATURIZATION AND
HARSH ENVIRONMENT
APPLICATIONS

DIAMFAB's unique know-how unleashes the semi-conductor potential of diamond

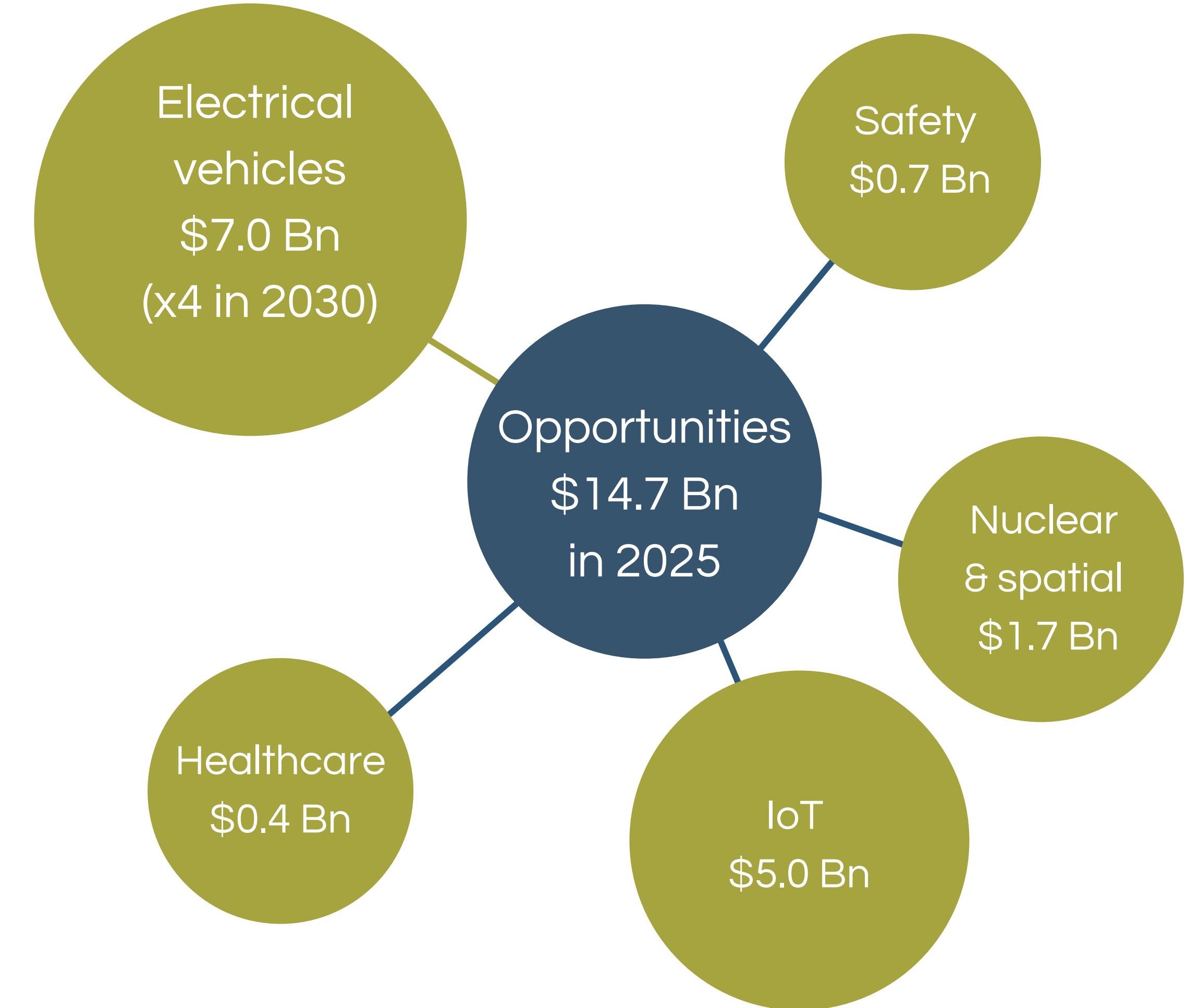


1- A diamond seed, methane (source of C), hydrogen and doping gases (boron, nitrogen) are the ingredients of DIAMFAB's diamond synthesis: epitaxy.

2- In controlled temperature and pressure conditions, we crack methane into carbon that rearranges as a doped diamond crystal at the surface of the seed

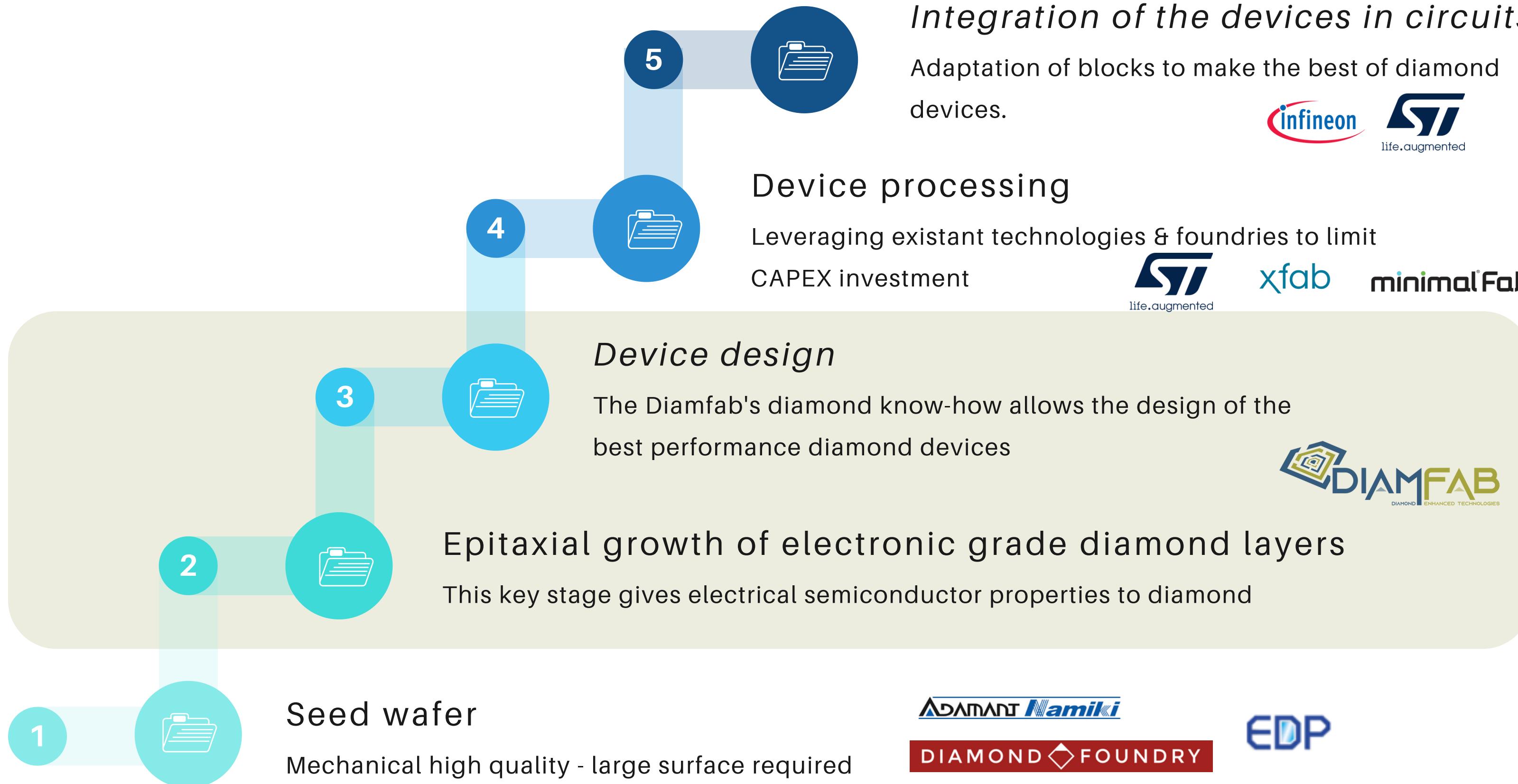
3- The high value-added wafer obtained includes active layers (electronic grade) and is ready for device fabrication.

Our high value-added diamond wafer can enter several sectors opening huge market opportunities





DIAMFAB key position in the value chain: at the interface between material and devices





Our go to market strategy based on co-development



High voltage capacitor for electrical car



Large Size Diamond Doped epitaxial
Synthetic Layers



20 year-long-life μ -battery for IoT
*made of diamond and recycled nuclear
waste (tritium)*





Our 2 business models with material and services

We turn a seed into a high-value added wafer ready for devices fabrication

HIGH VALUE-ADDED
WAFER + PROCESS

To Integrated Devices
Manufacturers

HIGH PERFORMANCES
DIAMOND DEVICES supplier



To end users or OSAT*
with a co-development
approach

Our management team & Leadership

With strong expertise in semi-conductors and innovation



Gauthier Chicot
CEO & co-founder

Ing. Polytech' Grenoble 2008
PhD. Université Grenoble Alpes 2013
10 years experience CEA, CNRS
Innovation Marketing EM Lyon 2019



Khaled Driche
CTO & co-founder

Master UCL (UK), UGA (FR) 2015
PhD. UGA 2018 & Tsukuba (JP) 2019
5 years experience in diamond transistor
Innovation Marketing EM Lyon 2019



Ivan Llaurado
CRO & partnership development director

Electrical engineering INSA Lyon 2004
Marketing and strategy EM Lyon 2005
16 years experience in Business development, team management
@ Schneider Electric

Our advisory board

Experienced members from big industrial players and successful start-ups



Cyril Menon
Advisor Industry

Executive Vice President Operations
@ SOITEC



Yann Roche
Advisor Management

Founder & COO of SynapCell



François Desmarest
Advisor finance

Operating partner & CFO
Serial entrepreneur (x6)



Christel Galbrun-Noel
Advisor Bus dev'

Mobility Segment President
@ Schneider Electric

Our scientific advisors

Diamond world-class scientists



Pr. Etienne Gheeraert
Scientific advisor & co-founder
University Professor @ Grenoble University - CNRS
& Tsukuba University
Diamond electronic devices



Pr. Julien Pernot
Scientific advisor & co-founder
University professor @ Grenoble University - CNRS
Electronic transport in diamond



David Eon, PhD
Scientific advisor & co-founder
Assistant professor @ Grenoble University - CNRS
Diamond synthesis

Our R&D team

With strong expertise on diamond from renowned research centers



Jessica Bousquet, PhD
R&D manager - Growth

8 years experience: diamant, MOS2,
graphene



Manoël Jacquemin, PhD
Engineer



Dov Nusimovici
Engineer



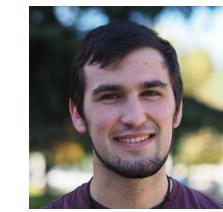
Mathieu Loyer
Engineer

Diamond synthesis & doping



Juliette Letellier, PhD
R&D manager - Devices

5 years experience: diamond diodes
and MOSFET



Elliott Corne
R&D technician



Damien Michez
Engineer

Devices fabrication & characterization



Mehdi Oujanba
Engineer





in few figures :



Awards :

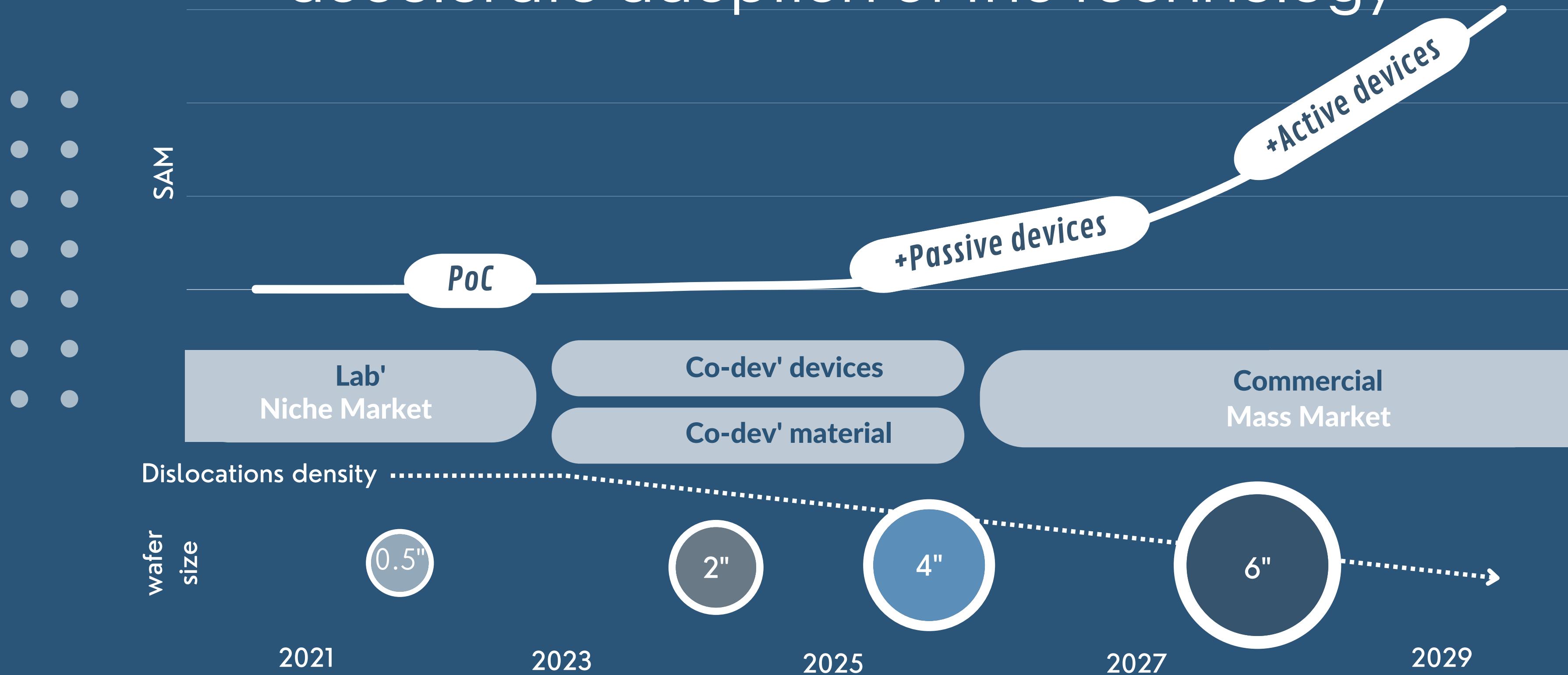


LE TROPHEE ROTARY
de la création d'entreprise





Our roadmap to lower unit costs and accelerate adoption of the technology

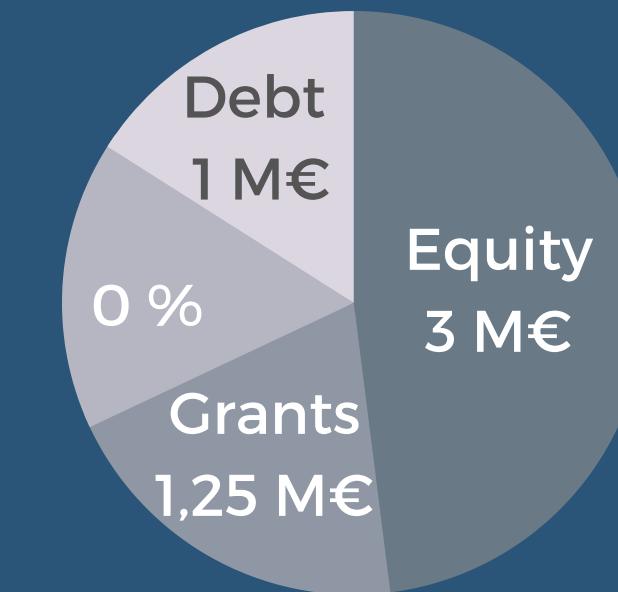




To accelerate our access to market

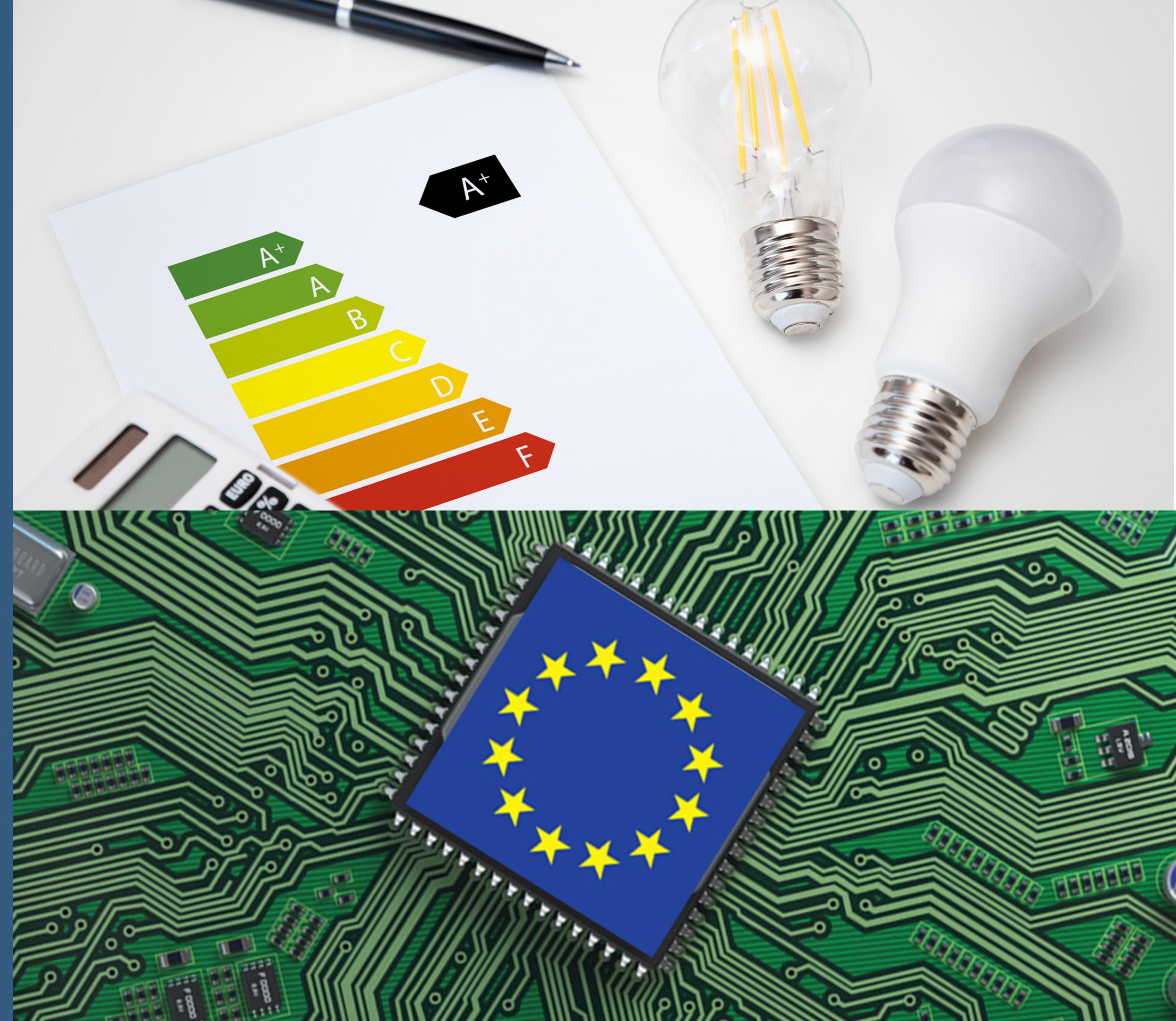
- Reach pilot scale: 4" wafers
- Demonstrate devices (capacitor & battery)

3 M€
SEED ROUND



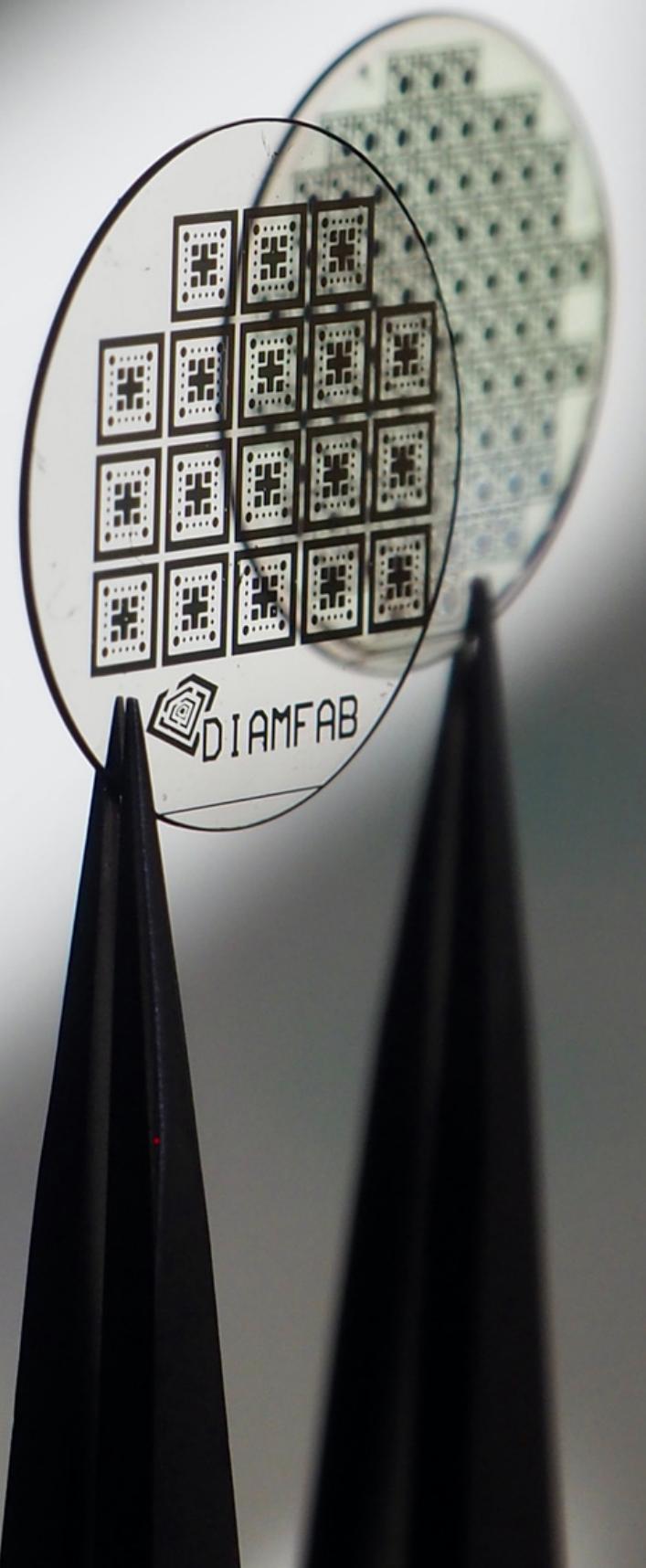


Disruptive
technology to
meet major
environmental
and economic
challenges





Thank you



Pitch Deck Presentation



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